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Substitution for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)			Complete if Known Application Number <u>101601756</u> Filing Date <u>June 20, 2003</u> First Named Inventor <u>Craig T. Swift</u> Group Art Unit <u>2815</u> Examiner Name _____ Attorney Docket Number <u>SC12828TP</u>	
Sheet	1	of	2	

U.S. PATENT DOCUMENTS

[illegible]

FOREIGN PATENT DOCUMENTS

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Examiner Signature	TAN T. NGUYEN	Date Considered	08/18/04
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Signature: _____ Date: _____ Considered: _____

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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
TNT	AD	EITAN, Boaz et al.; A Novel Localized Trapping, 2-Bit Nonvolatile Memory Cell; IEEE Electron Device Letters; November, 2000; Pages 543-545; Vol. 21; No. 11; IEEE	✓

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